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Structural and Optical Band Gap Engineering of Cu–Li Co-Doped NiO Nanostructures for Optoelectronic and Energy Applications

This study presents Cu- and Li-co-doped nickel oxide (NiO) nanostructures that exhibit significant improvements in structural and optical properties. NiO samples, including pure, singly doped, and co-doped versions, are synthesized using the hydrothermal method. The structural, optical, and morphological characteristics are analyzed through X-ray diffraction (XRD), UV-visible spectroscopy, and scanning electron microscopy (SEM). XRD results revealed enhanced crystallinity in NiO films due to dual doping, making these materials promising for microelectronics applications. Refractive index and absorption coefficient demonstrated improvements in NiO with both single and co-doping. The band gap energy decreased from 3.50 eV for Cu-doped NiO to 3.34 eV for Cu, Li co-doped films. This reduction in band gap suggests that Cu and Li co-doping significantly enhances the electrochromic performance of the NiO samples. The increased absorbance in the NCL7 sample underscores the potential for fine-tuning dopant levels to further improve performance.

Keywords: Metal oxides; Li co-doped NiO nano-films; Cu co-doped NiO films; Refractive index

1. INTRODUCTION

Oxide electronics encompasses a wide array of materials and devices, including dielectrics, ferroelectrics, piezoelectrics, epitaxial oxides, memory devices, and sensors. Metal oxide (MO) semiconductors fundamentally differ from traditional inorganic semiconductors, such as silicon and III–V compounds, in terms of material design strategies, electronic structure and interactions, charge transport and transfer mechanisms, defect chemistry, thin-film fabrication techniques, and optoelectronic properties [1]. These characteristics facilitate both the implementation of existing device functionality and the creation of wholly new apps [2]. The MOs can function as semiconductors, metals, or insulators, depending on their crystal structure and chemical composition. Their behavior can be tailored to be either n-type or p-type through doping. MO semiconductors, which support equilibrium populations of electrons and holes, are widely used in batteries, solar energy conversion, and display technologies [3], [4]. The discovery of hydrogenated amorphous silicon (a-Si)

and organic semiconductors opened new possibilities in thin-film transistors. However, its relatively low carrier mobility (around $0.5\text{--}1.0\text{ cm}^2\text{ V}^{-1}\text{ s}^{-1}$), lack of optical transparency, limited current-carrying capability, and moderate mechanical flexibility pose significant challenges to its use in future technologies [5].

Transport mechanisms in MOs are very different from those in silicon semiconductors, where hybridized sp^3 σ -bonding and sp^3 σ^* -anti-bonding states characterize the conduction band minimum and valence band maximum. In the metal oxides examined in this study, the valence band is primarily constituted by occupied oxygen 2p antibonding states. In contrast, the conduction band predominantly derives from unoccupied metal ns bonding orbitals. The spherical symmetry of the ns orbitals around the conduction band minimum results in low electron effective masses in these oxides, hence facilitating efficient electron transport even in the amorphous phase [6]. This phenomenon originates from the effective overlap of spherically symmetric metal s orbitals, which is largely insensitive to lattice distortions, unlike the strongly directional sp^3 σ orbitals in silicon that undergo pronounced mobility degradation in the amorphous phase. Consequently, amorphous oxide semiconductors (AOSs) often exhibit electron mobilities comparable to those of their crystalline counterparts. Moreover, the distribution of sub-bandgap density of states significantly

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varies between amorphous covalent semiconductors. The sub-bandgap density of states in amorphous indium-gallium-zinc oxide is generally one to two orders of magnitude lower than that seen in a-Si [7].

To address these issues, researchers have focused on MOs, which offer distinct advantages over crystalline Si and other III-V semiconductors. MOs demonstrate exceptional carrier mobilities, even in their amorphous forms, and are highly tolerant to mechanical stresses [8]. They are compatible with organic dielectric and photoactive substances and provide excellent optical transparency. Moreover, high-quality metal oxide thin films appropriate for electronic applications can be produced by vapor- and solution-phase techniques under near-ambient conditions (about 25°C). These attributes make MOs beneficial for high-value applications, including cost-effective circuits, flexible organic light-emitting diode (OLED) screens, and solar systems built on plastic substrates [9].

Transparent semiconducting oxide thin films are highly sought after due to their outstanding optical properties, extraordinary stability, and excellent electrical performance [10]. These transparent conducting oxides, fundamentally MO semiconductor materials, can be classified as either n-type or p-type. The demand for transparent, conductive thin-film coatings of p-type semiconductors in various optoelectronic applications is increasing. Transparent semiconducting oxide thin films are ideal materials for sustainable buildings and renewable energy systems due to their high transparency, electrical conductivity, and long-term durability. Their use in energy-efficient smart windows, transparent photovoltaics, and wind turbine blade coatings helps to improve energy efficiency and system performance, and boost the lifetime of the system [11,12]. Nickel oxide (NiO), the most extensively studied p-type transition-metal oxide, is a promising material for several usages. These function as positive electrodes in batteries, solar-thermal absorbers, electrochromic displays, hetero-junction solar cells, and gas sensors [13,14]. NiO is recognized for its wide band gap, low cost, and excellent cyclic stability, making it a promising material for ion storage [15].

In recent years, a significant number of studies have focused on tuning the electrochemical properties of NiO thin films by doping them with phosphorus [16], cobalt [17], aluminum [18], magnesium [19], lithium [20], indium [21], and others, employing various doping techniques. Multiple researches have indicated that co-doped NiO films, created using diverse fabrication techniques, demonstrate superior electrochromic performance relative to conventional monodoped NiO. For instance, Castro et al. [20] studied the structural properties of gradient Ni- and Mn-doped lithium cobalt oxide thin films produced by magnetron sputtering for lithium-ion batteries. The LMNCO thin films showed a clear compositional gradient throughout their thickness. Compared to virgin LCO, both LNCO and LMNCO showed significant redox activity, with LMNCO exhibiting superior Li-ion intercalation behavior and improved Mn redox performance. Hosseinzade et al. [21] investigated the structural and electrochemical properties of Cu-doped NiO nanostructures using electrochemical impedance spectroscopy. The optimized

NiO nanostructure containing 3% Cu exhibited markedly improved performance, characterized by an appropriate bandgap of approximately 3.38 eV, enhanced electrical conductivity (0.04 mS cm^{-1}), a larger electroactive surface area (1.430 cm^2), and superior charge carrier mobility ($1.36 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$). The structural properties of Li doped NiO films grown on FTO substrates through spin coating technique were irradiated using 60 MeV Si ions under swift heavy ion radiation (SHIR) [22].

It was reported that the effect of SHIR had a positive influence on the structural properties of Li:NiO films, as well as the intensities of the first-order (1LO) and second-order (2LO) Raman modes were found to decrease following Si ion irradiation, indicating the formation of irradiation-induced defects. Huang et al. [23] examined Li-Ti co-doped NiO films synthesized by the sol-gel spin coating method, revealing a notable optical fluctuation of over 56% at 580 nm. Similarly, Lin et al. [24] developed Li-Zr-NiO films using radio-frequency magnetron sputtering, achieved optimal optical modulations of 40% and 68% at 670 nm, respectively. Gillaspie et al. [25] also utilized radio-frequency magnetron sputtering to fabricate Li-W co-doped NiO films, which exhibited an optimal optical modulation of around 58%.

Chen et al. [26] explored Li-Cu co-doped NiO films fabricated via a chemical solution deposition technique. This co-doping approach significantly improved the transmittance and conductivity, highlighting the potential of Li-Cu co-doped NiO films as p-type transparent conducting oxides. In another study, Uzunbayır et al. [27] synthesized Li, Cu-NiO_x particles using the sol-gel method, maintaining a fixed Li content of 0.05 while varying the Cu content from 0 to 0.30. The authors found that incorporating Li⁺ and Cu²⁺ into the structure decreased both emission intensity and average decay time. Zhang et al. [28] documented the effect of lithium doping on the optoelectronic and transport properties of nickel oxide films. The films were produced using pulsed-laser deposition. The researchers noted that Li doping significantly improved the p-type conductivity of NiO; however, the room-temperature mobilities remained low across all films ($<0.05 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$). X-ray photoemission and O K-edge absorption spectroscopy revealed a shift of the Fermi level towards the maximum valence-band (MVB) and the formation of a new hole state due to Li doping.

The MVB and hole states predominantly consist of Zhang-Rice bound states, which account for the limited mobility [29]. Bhatt et al. [30] synthesized Li-doped NiO films using microwave synthesis and conducted first-principles simulations. Optical studies showed that the band gap of pure NiO decreased from 3.3 eV to 3.17 eV upon 1% Li doping. Additionally, the Li-doped NiO films exhibited increased electrical capacity and improved cyclability. Electrochemical impedance spectroscopy results indicated that the reversibility and conductance of Li-doped NiO films were significantly enhanced.

Chang et al. [31] examined Li-doped NiO electrochromic films fabricated using RF magnetron sputtering. Their findings indicate that Li doping markedly improves the performance of electrochromic devices by

augmenting charge storage capacity. The improved electrochromic device attained an intercalation charge of 11.93 mC/cm², an optical density variation of 0.38, a transmittance modulation of 44.1%, and a coloring efficiency of 31.8 cm²/C at 550 nm under 3.2 V.

Although earlier research has shown that Li- and Cu-doped NiO materials can enhance the optical, structural, and electrochemical performance of NiO-based thin films, most studies have concentrated on single-property enhancement or individual dopants, with little knowledge of the synergistic effects of Li–Cu co-doping. Majority of existing studies focus on optical and structural characterization, with insufficient emphasis on the electrochemical mechanisms governing charge transfer and stability. Additionally, there is a lack of systematic optimization of dopant concentration and synthesis conditions to balance optical transparency and conductivity. Further more, the long-term cycling durability and environmental stability of Li–Cu co-doped NiO films have not been comprehensively assessed. To tackle these research gaps, this study explores the structural and optical properties of Li_xCu_{0.05}Ni_{0.95–x}O nanocoatings with optimized Li concentrations. It highlights the synergistic role of Li–Cu co-doping for advanced solar energy and optoelectronic applications.

This work introduces a new class of hybrid Li_xCu_{0.05}Ni_{0.95–x}O nanocoatings engineered through controlled Li–Cu co-doping to simultaneously improve optical properties and visible-light transmittance, a combination not achieved in previous NiO-based studies. By optimizing Li content within a fixed Cu-doping framework, we reveal a synergistic electronic effect that modifies the band structure, enhances charge transport, and maximizes optical contrast relevant to solar applications. This integrated approach creates a new materials platform for high-performance solar and optoelectronic devices. This study used a hydrothermal method to prepare Li_xCu_{0.05}Ni_{0.95–x}O (x = 0.0, 0.02, 0.05, 0.07) nanoparticles (NPs) with varying Li contents (0, 2, 5, and 7%).

Moreover, the investigation thoroughly analyzes the effect of Li inclusion on crystal structure, phase purity, crystallite size, defect deformation, and local elemental distribution, thereby explaining the structural aspects that determine material attributes. The outcomes anticipated that Li–Cu co-doping has a synergistic structural function in customizing the NiO lattice and enhancing the microstructure, which leads to improved optical behavior and charge transport.

2. EXPERIMENTAL PROTOCOLS AND MATERIALS

2.1 Synthesis of Li_xCu_{0.05}Ni_{1–x}O Nanoparticles

Ni(NO₃)₂·H₂O, Cu(NO₃)₂·3H₂O, LiOH, and NH₄OH were obtained from Sigma-Aldrich and used without further treatment. Li_xCu_{0.05}Ni_{1–x}O nanoparticles (NPs) were synthesized using a hydrothermal method with varying stoichiometries, as outlined in Table 1. To begin, 0.035 mol of nickel nitrate hexahydrate (Ni(NO₃)₂·6H₂O) was dissolved in 70 mL of deionized water (DW). Copper (II) nitrate trihydrate (Cu(NO₃)₂·3H₂O) and lithium hydroxide (LiOH) were then added to the above solution at different molar ratios corresponding to Li_xCu_{0.05}Ni_{0.95–x}O

(where x = 0, 0.02, 0.05, and 0.07) while maintaining a constant copper content of 0.05 and adjusting the lithium content to 0, 2, 5, and 7%. A solution of ammonium hydroxide (NH₄OH) at a concentration of 0.1 mol in 100 mL of deionized water was incrementally added to achieve uniform distribution while stirring at ambient temperature. The reaction mixture was agitated for an extra hour at the same temperature. The formulated solution was introduced into a Teflon-lined stainless-steel autoclave and held at 180 °C for 8 hours to produce Li_xCu_{0.05}Ni_{0.95–x}O nanoparticles. The nanoparticles were washed several times with deionized water and centrifuged at 10,000 rpm for 5 minutes. The samples were then dehydrated in a vacuum oven at 70°C overnight. The samples were subsequently annealed in air at 270°C for 2 hours, then dispersed in ethanol to a concentration of 10 mg/mL. Figure 1 illustrates the synthesis technique for Li_xCu_{0.05}Ni_{0.95–x}O nanoparticles.

The previous studies, in the existing survey, showed that 5 mol % Cu provided an appropriate balance between enhanced electrical conductivity and improved optical absorption while preserving the single-phase NiO crystal structure. Therefore, in this study, 5 mol% Cu was chosen as a representative composition reported to provide structural stability while allowing the effect of Li concentration to be systematically investigated. All characterization devices were adjusted according to the manufacturers' recommended protocols before measurements were taken. The characterization techniques used demonstrated higher measurement accuracy and precision, ensuring the reliability and reproducibility of the derived structural, morphological, compositional, and optical properties. X-ray diffraction (XRD) assessments were conducted with an angular precision of ±0.02° (2θ). The field emission scanning electron microscopy (FESEM) accelerating voltage was kept within the instrument tolerance of ±1%. The uncertainty in the EDS elemental composition analysis was roughly at ±1–2 wt.% for the elements analyzed. UV–Vis absorption spectra were obtained with a wavelength precision of ±0.5 nm. The photoluminescence (PL) spectra were collected with a wavelength precision of ±0.3 nm. The film thickness determined using spectroscopic ellipsometry exhibited an uncertainty of roughly ±2–3 nm.

Table 1. Sample codes and stoichiometry of Li_xCu_{0.05}Ni_{0.95–x}O nanoparticles

Sample	Li	Cu	Ni _{0.95–x} O
NC	0	0.05	0.95
NCL2	0.02	0.05	0.93
NCL5	0.05	0.05	0.90
NCL7	0.07	0.05	0.88

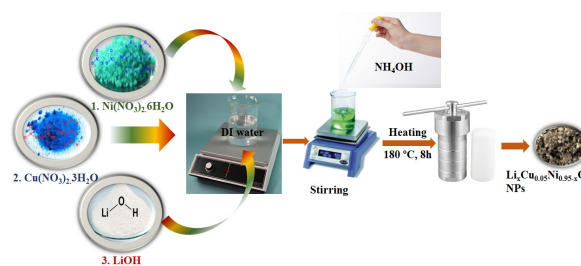


Figure 1. Schematic diagram for the synthesis process of Li_xCu_{0.05}Ni_{0.95–x}O

2.2 Characterization Techniques

The X-ray diffraction patterns of the prepared nanoparticles were examined for phase identification using a Rigaku Miniflex-II system with Cu/K α radiation ($\lambda = 1.5406 \text{ \AA}$). Fourier-transform infrared (FTIR) transmission spectra were recorded using a Smart iTR NICOLET iS10 instrument to analyze the bonding characteristics. The morphology and elemental composition of the prepared nanoparticles were characterized using scanning electron microscopy (SEM) and energy dispersive X-ray spectroscopy (EDS) with a JEOL SEM (Model: JSM6610LV). Absorption spectra, for all samples, were measured with a UV-Vis-NIR spectrometer (JASCO, Model: UV-670). Ellipsometry measurements were conducted using a J.A. Woolam ellipsometer (Model: M-2000).

3. RESULTS AND DISCUSSION

3.1 XRD Analysis of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ Films

Figure 2a shows XRD patterns of NiO nanoparticles (NPs) with different Li concentrations and fixed Cu concentrations. The XRD patterns reveal five strong peaks that correspond to (111), (200), (220), (311), and (222) planes of the cubic NiO phase (JCPDS no.73–1523). No impurity phases were observed in the doped and undoped XRD spectra, indicating that Li and Cu atoms were incorporated into the NiO lattice without altering its cubic structure [32]. The most intense peak was the (200) plane, which implies a preferred orientation along this direction. No peaks, other than the NiO peaks, were observed, indicating that Li and Cu atoms may be incorporated into the NiO lattice [33].

Furthermore, it could be seen that the diffraction peaks were slightly shifted to lower angles upon increasing the doping concentrations, suggesting that the doping process has increased the lattice constant of the NiO crystal [34]. Figure 2b illustrates the examination of the 2θ range of $43\text{--}44^\circ$ to demonstrate the impact of additions on structural modifications. The Debye-Scherrer and Bragg equations were used to calculate the crystallite sizes and d-spacing [34]:

$$D = \frac{K\lambda}{\beta \cos \theta} \quad (1)$$

$$d = \frac{n\lambda}{2 \sin \theta} \quad (2)$$

where $K = 0.94$ (Scherrer constant), $\lambda = 1.5405 \text{ \AA}$ (wavelength of Cu K α 1 radiation), θ = diffraction angle of the peak, β = full width at half-maximum (FWHM) of the peak, $n = 1$ (order of reflection). The average crystallite size of nanoparticles markedly decreased with increasing lithium concentration. The determined grain sizes of nanoparticles were 8.092, 8.057, 8.042, and 8.026 nm for lithium concentrations of 0, 2, 5, and 7%, respectively. Table 2 shows the calculated full-width half maximum (FWHM), average crystallite size, and d-spacing of planes for all the prepared $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ Films.

3.2 FTIR of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ Films

Figure 2c displays the FTIR spectra of all produced samples. The bands at 2933 cm^{-1} and 1367 cm^{-1} are attributed to the C-H stretching vibrations and O-C=O asymmetric stretching vibrations. Moreover, the absorption band appeared at 2344 cm^{-1} is correspondent to the CO_2 molecules in the air [35]. The observed band at 3410 cm^{-1} is associated with the O-H stretching vibrations of H_2O molecules adsorbed by Li and Cu-doped NiO-NPs. The absorption band at $\sim 1046 \text{ cm}^{-1}$ is assigned to different modes of Cu-O bending vibrations. In Figure 2d, the zoomed-in region ($1900\text{--}700 \text{ cm}^{-1}$) provides a closer look at specific vibrational features [34]. The green-shaded region, located between $1700\text{--}1600 \text{ cm}^{-1}$, is assigned to the stretching vibration of the C=O group, which could be related to residual organic materials or solvents used during film preparation. The orange-shaded area between $1300\text{--}1400$ is assigned to asymmetric stretching vibrations of the C=O group. Furthermore, the orange-highlighted area between $1000\text{--}1100 \text{ cm}^{-1}$ is associated with Cu-O stretching vibrations, indicating the successful incorporation of copper into the NiO lattice [36]. The slight variations in peak intensities across the spectra suggest differences in Li and Cu doping levels, influencing the vibrational characteristics and bonding environments within the doped NiO structure.

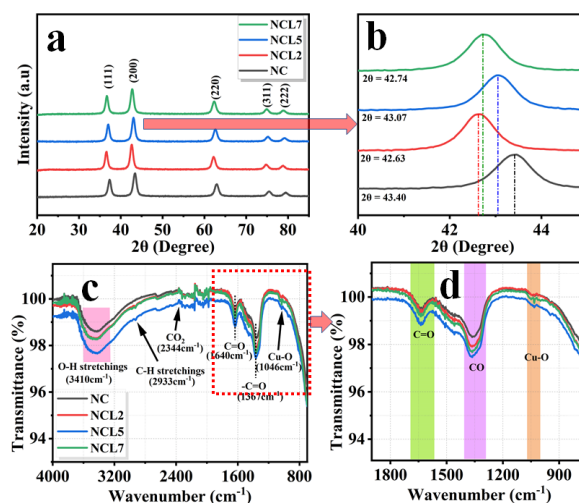


Figure 2. (a, b) X-ray diffraction patterns and (c, d) FTIR Fourier-transform infrared transmission spectra of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$

Table 2. Structural calculations of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ Films

Sample	Peak Position 2θ	FWHM $\beta(^{\circ})$	Crystallite size (D) (nm)	d_{200} (nm)
NC	43.4084	1.10349	8.092	0.284
NCL2	42.6316	1.10541	8.057	0.283
NCL5	43.074	1.10912	8.042	0.282
NCL7	42.7409	1.11006	8.026	0.281

3.3 Morphology Analysis of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ Films

Figure 3 illustrates the surface morphology of all produced samples. The SEM images demonstrate that the particles possess a porous architecture composed of nanoscale grains, indicating a well-dispersed structure.

The grains appear uniformly distributed, without any preferential orientation, a characteristic of the hydro-thermal synthesis technique. EDS mapping was conducted to further investigate the elemental composition, as shown in Figure 4. The mapping confirms a homogeneous distribution of key elements throughout the sample matrix, including Ni, O, and Cu. Due to EDS's technical limitations, it is common for Li to not appear in the elemental mapping even when it is present in the sample. The uniform distribution suggests that the doping process was successful and that no significant segregation or clustering of dopant atoms was observed. The presence of well-dispersed Ni, O, and Cu within the porous nanostructure may enhance the electronic and catalytic properties of the doped NiO films, making them suitable for various energy conversion and storage applications.

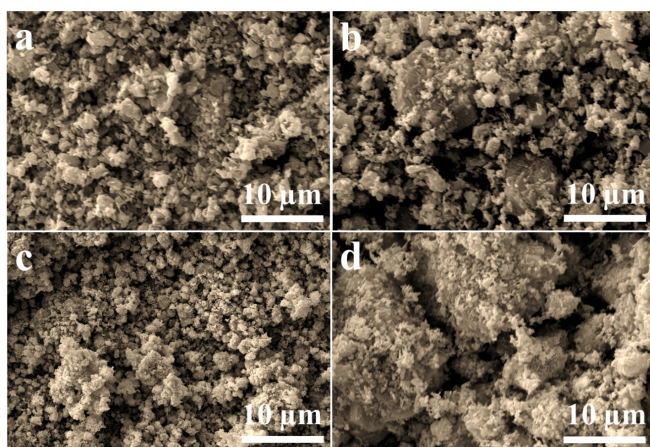


Figure 3. Scanning electron microscopy images of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ for (a) $x = 0\%$, (b) $x = 2\%$, (c) $x = 5\%$, and (d) $x = 7\%$

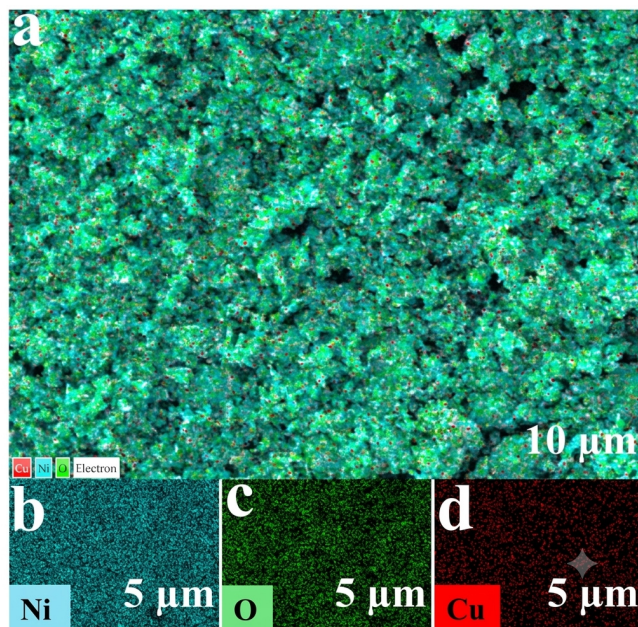


Figure 4. Energy dispersive X-ray spectroscopy of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ for $x = 2\%$ for (a) Mix, (b) Ni, (c) O, and (d) Cu

Moreover, the SEM image revealed a densely packed granular structure composed of uniformly distributed fine particles with interconnected grains, indicating successful formation of the Cu- and Li-doped

NiO structure without noticeable phase segregation. The corresponding EDS elemental mapping confirms a homogeneous distribution of Ni, O, and Cu throughout the sample, while the mixed elemental map demonstrates excellent compositional uniformity. The absence of Cu-rich agglomerates suggests that Cu is effectively incorporated into the NiO matrix, supporting the formation of a chemically homogeneous doped oxide with high structural integrity.

3.4 UV-Vis of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ Films

UV-Vis spectroscopy was used to investigate the optical properties of NiOx films with varying Li concentrations. Figure 5a displays the optical absorbance spectra for Cu-doped NiO and Cu & Li co-doped thin films, spanning the wavelength range of 280 nm to 900 nm. The absorption profile demonstrates notable alterations in the optical characteristics of Li- and Cu-doped NiO films, as evidenced by a redshift of the absorption edges, a decrease in the band gap, and changes in the absorption coefficient. The findings indicate that co-doping with Cu and Li can effectively modulate the electrical and optical properties of NiO, making it a promising material for diverse applications, including photocatalysis, solar cells, and energy storage devices.

The higher absorbance of the NCL7 sample suggests the potential for tailored dopant concentrations to enhance performance. The spectra show reduced absorption in the visible region, confirming that undoped NiO has minimal light absorption in this range. However, the doped samples, particularly NCL7, exhibit a notable increase in absorbance in the visible range. This could result from the introduction of Li and Cu ions, which create additional defect levels or states, thereby allowing the films to absorb more visible light.

The observed enhancement in visible-light absorption could significantly impact applications such as photocatalysis, where visible-light activation is desirable, underscoring the relevance of this research in the field. All samples show low absorption in the infrared region, with NCL7 again showing a slight increase. This slight increase in infrared absorbance could reflect dopant-related changes in the material's electronic structure, although it remains minimal compared to the UV and visible regions.

Figure 5b offered an enlarged view of the UV region, providing further insight into the optical behavior of the Li and Cu-doped NiO films across different doping levels. In the UV region, a pronounced absorption peak is visible for all samples, consistent with the band-to-band electronic transitions in NiO. The absorbance intensities vary among the samples, with NCL7 (green) showing the highest absorption, indicating enhanced light harvesting due to increased dopant concentrations. The broadening of the absorption peaks with increased doping, especially for the NCL7 sample, suggests a possible increase in defect states or changes in the crystal structure, which may create localized energy levels within the band gap. These novel findings will pique the interest of researchers in the solar and semiconductor fields.

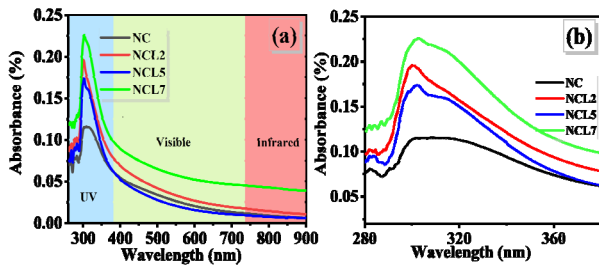


Figure 5. Absorbance value of the dispersion solution of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ NPs in (a) wide range and (b) short range

Figure 6a shows the absorption coefficient of NiO_x films. The absorption coefficient values were reduced with the increase in Li content. As expected, the absorption coefficient decreased in the visible range for the doped samples relative to NC, aligning with the observed reduction in absorption in the UV-visible spectra. Higher doping levels, particularly in NCL7, cause a more pronounced decrease in the absorption coefficient, indicating changes in electronic transitions. However, the high absorption coefficient in the UV region persists across all samples, validating the material's ability to absorb UV light efficiently, although doping tunes this property. The optical direct bandgaps (E_g) of all the prepared NiO_x films were determined from the absorbance data by Tauc plots (Figure 6b) as reported in Ref. [37];

$$\alpha h\nu = \beta(h\nu - E_g)^2 \quad (3)$$

Here, $h\nu$ and α denote the photon energy and the absorption coefficient, respectively, computed using the formula $\alpha = 2.303A/t$, where A represents absorbance and t signifies film thickness. The constant β denotes the band edge parameter.

Table 3 tabulates the obtained E_g values for NC, NCL2, NCL5, and NCL7, respectively. The doped samples exhibited progressively lower band gaps as the doping concentration increased, with NCL7 having the smallest band gap. This result demonstrates that co-doping NiO with Cu and Li is an effective strategy to narrow the band gap, which could enhance its potential for applications such as photocatalysis or solar energy conversion.

Table 3. Calculated bandgap of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ Films

Sample	Band gap (eV)
NC	3.50
NCL2	3.45
NCL5	3.35
NCL7	3.34

Figure 6c presents the relationship between the absorption coefficient and the band gap with two y-axes. The absorption coefficients of specific wavelengths (1000, 800, 600, and 400 nm) for all samples (NC, NCL2, NCL5, and NCL7) are plotted on the primary y-axis. The corresponding band gaps for each sample are plotted on the secondary y-axis. This dual-axis plot helps visualize how Cu and Li doping levels simultaneously affect the optical absorption properties and the electronic band structure.

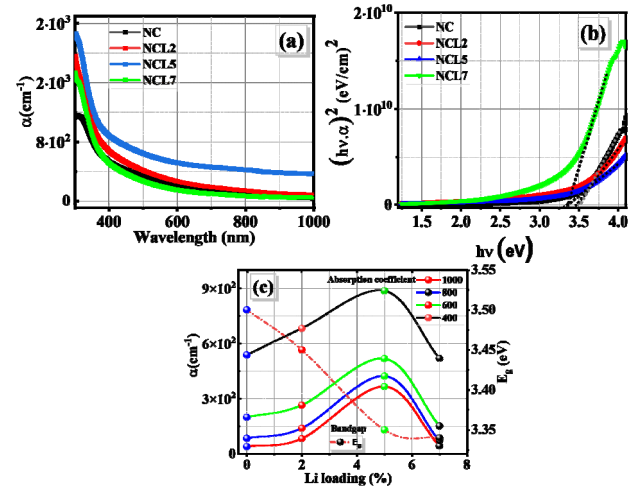


Figure 6. (a) Absorption coefficient, (b) Tauc's plot, and (c) absorption coefficient with Li content of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ films

At higher wavelengths (1000 nm and 800 nm), the absorption coefficients for all samples are relatively low, indicating weak absorption in the infrared region, which is expected for NiO -based materials. However, as the wavelength decreases to 600 nm and 400 nm, an increase was observed in the absorption coefficient, especially for the undoped NC sample, which aligns with its larger band gap. The doped samples (NCL2, NCL5, and NCL7) exhibited progressively lower absorption coefficients at these wavelengths, indicating that doping reduces the material's ability to absorb light in this region due to band gap narrowing.

The secondary y-axis displays the corresponding band gaps for each sample, showing a clear decreasing trend with increased doping concentrations. NCL7 has the highest doping level and exhibits the smallest band gap. This decrease in the band gap correlates with the redshift in absorption seen in the UV-visible spectra (Figures 3a and b). The plot revealed a clear inverse relationship between the band gap and the absorption coefficient at lower wavelengths (400-600 nm), where the doped samples absorb less light as their band gap decreases. This combined analysis in Figure 4c demonstrates that increasing Cu and Li doping reduces the band gap and decreases the absorption coefficient at higher wavelengths. This behavior is consistent with that observed in Figure 3 and Figures 4a and b. The dual-axis plot clearly illustrates the tunability of the optical properties of NiO films via doping, making them suitable for applications requiring narrow band gaps and controlled absorption characteristics, such as photovoltaic and optoelectronic devices.

The absorption profile demonstrates notable alterations in the optical characteristics of Li- and Cu-doped NiO films, as evidenced by a redshift of the absorption edges, a decrease in the band gap, and changes in the absorption coefficient. The findings indicate that co-doping with Cu and Li can effectively modulate the electrical and optical properties of NiO , making it a promising material for diverse applications, including photocatalysis, solar cells, and energy storage devices. The elevated absorbance of the NCL7 sample suggests the potential for tailored dopant concentrations to enhance performance.

3.5 PLS of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ Films

The structural modifications observed from XRD and the morphological evolution revealed by FESEM are expected to influence the electronic structure and defect density of the Cu–Li co-doped NiO nanostructures. Therefore, Photoluminescence spectroscopy (PLS) analysis was performed to investigate the effect of these structural changes on the radiative recombination behavior of charge carriers. PLS is a non-contact, non-destructive technique widely used to evaluate the optical quality of thin-film materials. In this method, the sample is irradiated with electromagnetic radiation of an appropriate wavelength, resulting in photon absorption and the promotion of charge carriers to higher-energy electronic states. As these excited electrons return to lower energy states, they recombine with photo-generated holes, emitting photons with slightly lower energy. Several factors, including the energy gap between the higher and lower states, the quality of the thin film, the nature of the dopant, and the presence of impurities and defect states, influence the energy of the emitted photons [38]. The PLS of undoped and Li, Cu, co-doped NiO NPs excited at 320 nm are shown in Figure 5a. The PL spectra of all the Li, Cu-co-doped NiO films showed four peaks at 365 nm, 407 nm, 434 nm, and 494 nm. The peak at approximately 365 nm presumably signifies near-band-edge emission in the ultraviolet range, typically ascribed to exciton recombination (bound electron-hole pairs) or transitions between shallow defect states adjacent to the conduction band edge.

In NiO, this emission may arise from intrinsic defects, such as oxygen vacancies or nickel interstitials, that generate defect levels near the conduction or valence band. The peak at 407 nm resulted from stock shift (certain defects) and band-to-band recombination, whereas the peak at 434 nm is likely due to near band edge emission triggered by exciton–exciton recombination [39].

The structure exhibits a significant defect density, as indicated by the emission peaks in the visible spectrum. The transitions responsible for the highest excitation at 320 nm involved the oxygen 2p states in the valence band and the nickel 3d levels in the conduction band. The emission band at 494 nm resulted from the recombination of electrons in the Ni^{2+} vacancy with holes in the valence band. Doping with Li^+ and Cu^{2+} decreased the photoluminescence emission intensity, indicating an increased recombination rate of photo-generated carriers in the NiO nanoparticles. The addition of Li^+ and Cu^{2+} decreased the recombination rate [40]. The decrease in PL intensity highly depended on the crystallite size, as confirmed by XRD results. The decrease in PL intensity highly depended on the crystallite size, as confirmed by XRD results.

3.6 Refractive index of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ Films

The refractive index (n) of a material is defined as the ratio of the speed of light in a vacuum to its phase velocity in the medium. Electromagnetic radiation, as it traverses a medium, experiences dispersion, scattering,

attenuation, and absorption. Thus, the refractive index is more accurately defined as a complicated, frequency-dependent parameter that delineates both phase propagation and energy dissipation of the electromagnetic wave as estimated in Ref. [41]:

$$n^* = n + ik \quad (4)$$

$$n = \left(\frac{1+R}{1-R} \right) + \sqrt{\frac{4R}{(1-R)^2} - k^2} \quad (5)$$

where R is the reflectance of the material and k is the extinction coefficient. The values of n and k , as a function of wavelength (λ) functions offer insights into the local field and electronic polarizability of ions, as depicted in Figures 6a and b, respectively. The Co-doped NiO samples demonstrated an enhanced refractive index. The findings indicated that Cu and Li co-dopants contributed to a greater increase in refractive index than single doping due to the higher polarization of Cu and Li atoms within the NiO lattice structure [42].

Effective permittivity is concerned with mixtures when the inclusions are seen as a continuous random medium rather than as discrete. Dinulović and Rašuo [43] introduced an analytical technique for estimating the loss tangent and material dielectric constant for composite materials. In another study, they proposed an effective model for predicting the dielectric constant and loss tangent of epoxy composites reinforced with hollow ceramic spheres and E-glass fibers. The model showed better agreement with experimental at lower volume fractions of hollow ceramic spheres in the epoxy matrix [44].

To further validate the structural and optical modifications discussed in the previous sections, the optical constants were analyzed using spectroscopic ellipsometry. Figure 6b illustrates that the k value for the pure NiO sample was the lowest, suggesting that the NiO host lattice contained minimal defects. As the doping concentration in the NiO sample increased, the k values also enhanced, reaching a maximum at $x=0.05$, which is attributed to an increase in defects within the host lattice.

Ellipsometry measurements were performed to determine the optical constants of the $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ films. The experimental data were fitted to models using the "CompleteEASE" software. A bi-layer system was employed for the modeling, and discrepancies were minimized using the Levenberg–Marquardt algorithm [45]. The real (ϵ_1) and imaginary (ϵ_2) parts of the dielectric constant for the prepared samples were obtained from the following equations [45]:

$$\epsilon_1 = n^2 - k^2 \quad (6)$$

$$\epsilon_2 = 2nk \quad (7)$$

The fitted data for ϵ_1 and ϵ_2 as functions of wavelength are shown in Figures 7a and 7b, respectively. Initially, both ϵ_1 and ϵ_2 decrease rapidly for $\lambda < 380$ nm, then exhibit a slight decrease over the range of 370–1500 nm. These results indicate that co-doping enhances the optical response of the NiO film. As shown in Figure 7(a), ϵ_1 is high in the UV region and gradually stabilizes in the visible–NIR range, showing strong

electronic polarization from inter-band transitions. Doping with Cu and Li alters ϵ_1 , with NCL7 displaying slightly lower values at longer wavelengths, suggesting reduced polarizability due to Li-induced lattice distortions. Figure 7(b) demonstrates that ϵ_2 , which relates to dielectric losses, decreases sharply with wavelength; NCL2 and NCL5 have higher ϵ_1 in the UV region due to increased absorption from Cu–Li co-doping. NCL7's lower ϵ_2 indicates diminished optical losses, making it suitable for low-loss optoelectronic devices.

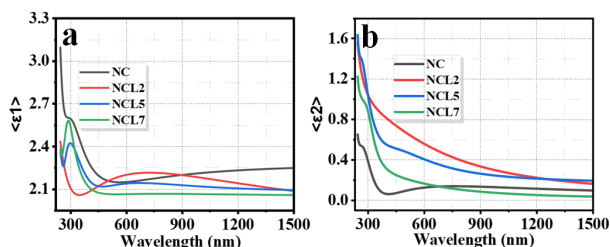


Figure 7. (a) Epsilon (ϵ_1) and (b) Epsilon (ϵ_2) of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ films

Ellipsometric measurements (Figure 8) reveal that ψ remains high in the UV and stabilizes across the visible–NIR spectrum, with NCL7 showing increased ψ , indicating stronger light–matter interactions. Figure 8a shows the wavelength-dependent average visual transmittance of untreated and coated (NCL2, NCL5, and NCL7) samples. All coatings show a quick rise in transmittance in the UV-visible range (300–500 nm), followed by a steady response of 21–22% across visible and near-infrared wavelengths. NCL7 has the highest and most uniform transmittance across a large spectral range, while NCL2 exhibits a modest drop in the mid-wavelength area before progressively rebounding. On the other hand, the phase difference Δ in (Figure 8b) quickly decreases with wavelength; higher values for NCL2 and NCL5 reflect stronger UV absorption, while NCL7 exhibits a smoother decay, indicating reduced losses. Overall, these findings demonstrate that Cu–Li co-doping enables precise tuning of the dielectric and optical properties, providing a route to optimize $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ films for solar energy harvesting, anti-reflective coatings, and other optoelectronic applications.

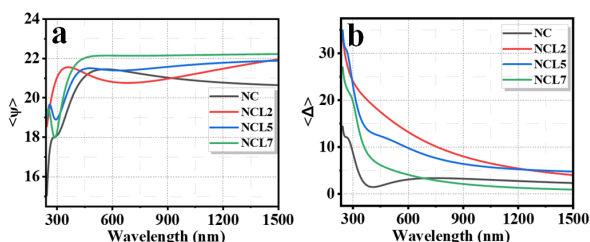


Figure 8. (a) Psi (ψ) ;(b) Delta (Δ) of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ films

The refractive index (n), extinction coefficient, and how the refractive index depends on Li content are shown in Figures 9a, b, and c, respectively. Figure 9a depicts the fluctuation of the refractive index with wavelength for both untreated (NC) and coated samples (NCL2, NCL5, and NCL7). All samples show normal dispersion, with a significant drop in the ultraviolet area (250–400 nm) and gradual stabilization at 1.40–1.50 in the visible and near-infrared regions. Among the coated

samples, NCL7 has the lowest refractive index throughout the spectrum, while NCL2 revealed a slightly higher value after 400 nm. The coated films showed and stabilized refractive index indicates better optical properties, making them appropriate for anti-reflective coatings. Moreover, for all the films, there was a sharp decrease in the UV region, followed by a gradual increase in the visible–near IR range, indicating normal dispersion in all the films. Li doping mainly increased the n throughout the whole spectrum, which results in enhanced densification and polarizability of NiO films. The NCL7 sample exhibits the highest n values, indicating that Li doping improves electronic interactions and reduces structural defects, thus increasing the optical density of the coating. The extinction coefficient (k) (Figure 9b) shows significant absorption in the UV region, then a steep decline into the visible range. Overall, it was observed that k shows an inverse relationship with Li loading: high Li content results in lower k , especially above 350 nm, indicating fewer electronic defect states and sub-bandgap absorption. The NCL7 film exhibited the lowest k values, indicating better optical transparency and fewer non-radiative recombinations. This reduction in absorption with Li doping is beneficial for developing high-performance optical coatings and low-loss optoelectronic layers.

Figure 9c shows how n varies with Li content at selected measurement wavelengths (400–1200 nm). The maximum increase was observed at $x=0.05$, followed by a gradual decline, indicating that the optimal Li loading for polarizability and compaction is at $x=0.05$ [46]. Beyond this concentration, excess Li may agglomerate into phases or disrupt lattice ordering, resulting in a slight reduction in n . The consistent behavior across all wavelengths confirms the strong influence of Li on the optical constants of films. The observed variation in refractive index and extinction coefficient aligns with the changes in crystallinity, grain size, and defect concentration identified by XRD, FESEM, and PL analyses, indicating that Cu–Li co-doping systematically alters the electronic structure of NiO.

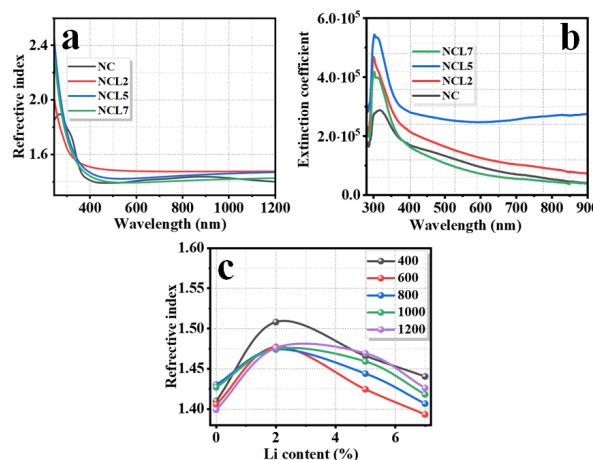


Figure 9. (a) Refractive index vs. wavelength, (b) Extinction coefficient vs. wavelength, and (c) refractive index with Li content of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ films.

Figure 10a presents the room-temperature photoluminescence spectra of the undoped NC and Li-doped samples. Four emission peaks at 365, 407, 434, and 494

nm are observed and correspond to intrinsic band-edge transitions and defect-related emissions. Li incorporation enhances PL intensity across all emission bands, with NCL7 showing the strongest emission. This enhancement reflects reduced non-radiative recombination, suppression of defect-mediated quenching, and improved activation of radiative centers.

The strong blue emission (407–434 nm) also underscores the suitability of the films for optoelectronic and visible-light-emissive applications [47]. Figure 10b shows how PL intensities at major emission peaks (365, 407, 434, 494 nm) evolve with increasing Li content. For all emission wavelengths, PL intensity increases monotonically up to 5% Li, after which the intensity slightly decreases. This trend demonstrates an optimal Li concentration that maximizes radiative recombination through defect passivation and improved crystallinity. Beyond this level, excessive Li can introduce new defects or disrupt the local electronic environment, diminishing emission efficiency. The peak enhancement at 5% Li directly correlates with the trends observed in Figure 9c, reinforcing the link between structural quality, optical constants, and luminescent performance [48].

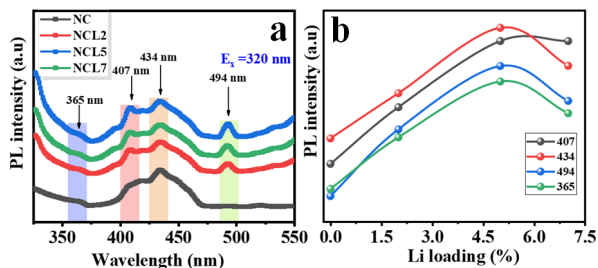


Figure 10. (a) Photoluminescence (PL) and (b) PL with Li content

4. PRACTICAL APPLICATIONS

The synthesized $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ nanocoatings in this investigation demonstrate promise for advanced transparent optoelectronic and sustainable energy applications due to their adjustable structural and optical properties attained by regulated Li–Cu co-doping. These materials are ideal for transparent photovoltaic cells, electrochromic smart windows, thin-film transistors, photodetectors, light-emitting devices, gas sensors, and transparent p-type electrodes due to their optimized crystal structure, tailored bandgap, increased visible-light absorption, and improved dielectric and refractive index properties. Additionally, their superior optical sensitivity and structural stability offer great potential for solar thermal absorber coatings, photo-catalytic reactors, anti-reflective coatings, and protective optical coatings utilized in industrial energy systems.

5. CONCLUSIONS

In this work, a systematic study of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ films was conducted to examine the effect of Li doping within a fixed Cu-doped framework on the optoelectronic and structural properties of NiO. The incorporation of Li preserved the single-phase crystal structure of NiO. However, it consistently increased the lattice parameter and decreased the crystallite size of the

NiO film. These structural changes led to a redshift of the absorption edge, a reduction in the band gap at $x = 0.07$, and a decline in the extinction coefficient across the visible spectrum. Moreover, the ellipsometry analysis confirmed that by adjusting the Li content, the dielectric constants and refractive indices could be tuned, allowing precise control over optical confinement and polarization in NiO films. Additionally, the photoluminescence analyses revealed an optimal Li doping level of $x=0.05$, indicating that at this level, radiative recombination was maximized due to enhanced crystallinity and reduced nonradiative losses.

In conclusion, the results demonstrated the synergistic effect of co-doping Li and Cu. Li helped to tune the band structure and optical constants, while Cu stabilized defect-mediated transitions. This synergistic effect allows the NiO films to customize their refractive index, optical, and luminescent properties traits that are essential for designing next-generation solar cell harvesting layers, optoelectronic interfaces, and electrochromic coatings. The demonstrated tunability positions $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ as a versatile materials platform, and the insights gained here can guide future optimization of p-type transparent conducting oxides for high-efficiency device applications.

6. LIMITATIONS AND FUTURE WORK

This study shows that Li-Cu co-doping improves the structural and optical properties of $\text{Li}_x\text{Cu}_{0.05}\text{Ni}_{0.95-x}\text{O}$ nanocoatings. However, it only focuses on material fabrication and physicochemical characterization under laboratory testings. Comprehensive electrical and electrochemical characterisation, long-term environmental and thermal stability evaluations, and the commissioning of prototype devices to verify optimal performance should all be part of future research. Furthermore, the optimization of the Cu/Li doping ratio and deposition parameters, as well as integration into transparent photovoltaics, electrochromic devices, and other optoelectronic systems should establish the material's potential for large-scale industrial and renewable energy applications.

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NOMENCLATURE

AOS	Amorphous Oxide Semiconductors
DW	Deionized Water
EDS	Energy Dispersive X-Ray Spectroscopy
FESEM	Field Emission Scanning Electron Microscopy
FTIR	Fourier-Transform Infrared
FWHM	Full-Width Half Maximum
MVB	Maximum Valence-Band
MO	Metal Oxide
NPs	Nanoparticles
NCL	Sample Designation

NIR	Near-Infrared
LMNCO	Lithium Manganese Nickel Cobalt Oxide
OLED	Organic Light-Emitting Diode
PLS	Photoluminescence Spectroscopy
SEM	Scanning Electron Microscopy
SHIR	Swift Heavy Ion Radiation
UV	Ultraviolet
UV-Vis	Ultraviolet–Visible Spectroscopy
XRD	X-Ray Diffraction

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**ИНЖЕЊЕРИНГ СТРУКТУРНИХ СВОЈСТАВА
И ЕНЕРГЕТСКОГ ПРОЦЕПА NiO
НАНОСТРУКТУРА КО-ДОПИРАНИХ БАКРОМ
И ЛИТИЈУМОМ ЗА ПРИМЕНЕ У
ОПТОЕЛЕКТРОНИЦИ И ЕНЕРГЕТИЦИ**

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Ова студија представља наноструктуре никл-оксида (NiO) ко-допирание бакром (Cu) и литијумом (Li), које показују значајна побољшања структурних и оптичких својстава. Узорци NiO – укључујући чисти NiO, као и верзије допирание једним елементом или ко-допирание – синтетисани су хидротермалном методом. Структурне, оптичке и морфолошке карактеристике анализиране су помоћу дифракције X-зрака (XRD), UV-видљиве спектроскопије и скенирајуће електронске микроскопије (SEM). Резултати XRD анализе открили су побољшану кристалност NiO филмова услед двоструког допирања, што ове материјале чини перспективним за примене у микроелектроници. Индекс преламања и коефицијент апсорпције показали су побољшања код NiO узорка, како при једноструком, тако и при ко-допирању. Енергија енергетског процепа смањила се са 3,50 eV код NiO допираног бакром на 3,34 eV код филмова ко-допираних бакром и литијумом. Ово смањење енергетског процепа указује на то да ко-допирање бакром и литијумом значајно побољшава електрохромне карактеристике NiO узорка. Повећана апсорбанција код узорка NCL7 истиче потенцијал за прецизно подешавање нивоа допаната ради даљег побољшања перформанси.